

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







EClamp2410PQ ESD Protection Device for T-Flash/MicroSD Interfaces

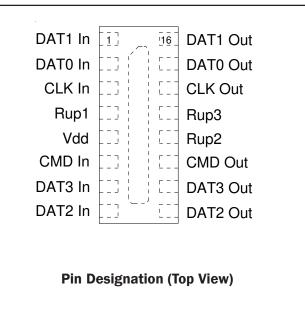
PROTECTION PRODUCTS - EMIClamp®

Description

The EClamp®2410PQ is a combination EMI filter and line termination device with integrated TVS diodes for use on Multimedia Card interfaces. This state-of-the-art device utilizes solid-state silicon-avalanche technology for superior clamping performance and DC electrical characteristics. They have been optimized for protection of **T-Flash/MicroSD interfaces** in cellular phones and other portable electronics.

The device consists of six circuits that include series impedance matching resistors and pull up resistors as required by the SD specification. TVS diodes are included on each line for ESD protection. An additional TVS diode connection is included for protection of the voltage (Vdd) bus. Termination resistor value of 45 Ohms is included on the DATO, DAT1, DAT2, DAT3, CMD, and CLK lines. Pull up resistors of 15k Ohms are included on DATO, DAT1, DAT2, and CMD lines while a 50k Ohm pull up is inlouded on the DAT3 line. These may be configured for devices operating in SD or SPI mode . The TVS diodes provide effective suppression of ESD voltages in excess of ±15kV (air discharge) and ±8kV (contact discharge) per IEC 61000-4-2, level 4. The EClamp2410PQ is in a 16-pin, RoHS/WEEE compliant, SLP4016P16 package. It measures 4.0 x 1.6 x 0.58mm. The leads are spaced at a pitch of 0.5mm and are finished with lead-free NiPdAu. The EClamp2410PQ is qualified to AEC-Q100 Grade1 for Automotive use.

Pin Configuration



Features

- ◆ Bidirectional EMI/RFI filtering and line termination with integrated ESD protection
- ◆ ESD protection to IEC 61000-4-2 (ESD) Level 4, ±15kV (air), ±8kV (contact)
- ◆ TVS working voltage: 5V
- lacklosh Termination Resistors: 45 Ω
- lacktriangle Pull Up Resistors: 15k Ω (3 each) and 50k Ω
- ◆ Typical Capacitance per Line: 12pF (VR = 2.5V)
- Protection and termination for six lines + Vdd
- Solid-state technology
- ◆ AEC-Q100 Grade1 Qualified

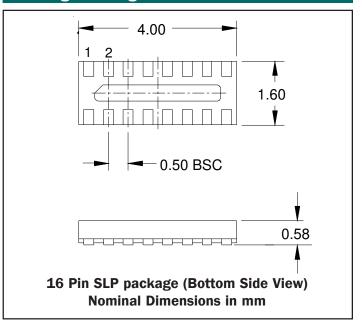
Mechanical Characteristics

- ◆ SLP4016P16 16-pin package
- ◆ RoHS/WEEE Compliant
- ◆ Nominal Dimensions: 4.0 x 1.6 x 0.58 mm
- Lead Pitch: 0.5mm
- Lead finish: NiPdAu
- Marking: Marking Code
- Packaging: Tape and Reel

Applications

- ◆ T-Flash / MicroSD Interfaces
- MMC Interfaces
- CDMA, GSM, 3G Cell Phones
- Automotive Applications

Package Configuration





Absolute Maximum Ratings

Rating	Symbol	Value	Units
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V _{ESD}	+/- 17 +/- 12	kV
Junction Temperature	T,	125	°C
Ambient Operating Temperature	T _A	-40 to +125	°C
Storage Temperature	T _{STG}	-55 to +150	°C

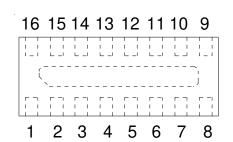
Electrical Characteristics (T=25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units		
TVS Reverse Stand-Off Voltage	V _{RWM}					5	V	
TVC Dayawaa Draakdayya Valtaga		I = 4 m A	$T_{A} = 25^{\circ}C$	6	8	10	V	
TVS Reverse Breakdown Voltage	$V_{_{BR}}$	I _t = 1mA	T _A = 125°C	6		10		
TVC Developed Legislate Comment	I _R	V 0.0V	T _A = 25°C			0.5	μΑ	
TVS Reverse Leakage Current		V _{RWM} = 3.0V	T _A = 125°C			100		
Series Resistors	R	Each Line		38	45	52	Ohm	
DAT Pull Up Resistor 1	R _{up1}		12	15	17	kOhm		
DAT Pull Up Resistor 2	R _{up2}			42	50	58	kOhm	
Total Canacitanas		Input to Gnd,	$T_{A} = 25^{\circ}C$	10	12	15		
Total Capacitance	C _{in}	Each Line V _R = 2.5V, f = 1MHz	T _A = 125°C		15	20	pF	

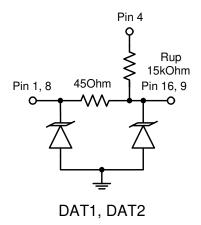


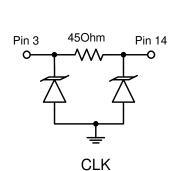
Pin Identification and Configuration

Pin	Symbol	Identification
1, 16	DAT1	Data line #1 input/output with pull-up resistor
2, 15	DATO	Data line #0 Input/Output
3, 14	Clock	Clock line Input/Output
4	Rup1	15K Pull-up resistor from DAT1 & DAT2
5	Vdd	Power Supply ESD Protection
6, 11	CMD	Command Line Input/Output
7, 10	DAT3	Data line #3 input/output with pull-up resistor
8, 9	DAT2	Data line #2 input/output with pull-up resistor
12	Rup2	50K Pull-Up Resistor from DAT3
13	Rup3	VCC Circuit 3A
Center tab	GND	Ground connection

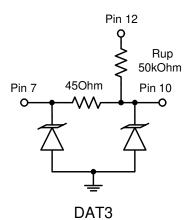


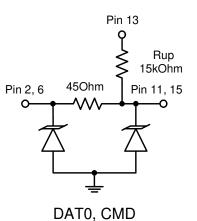
Schematics and Component Values







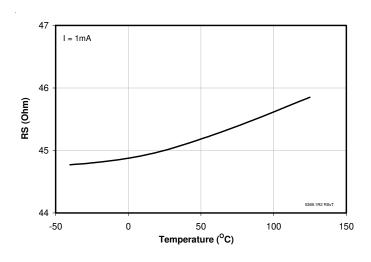




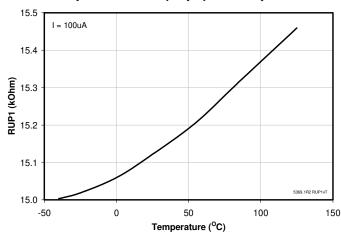


Typical Characteristics

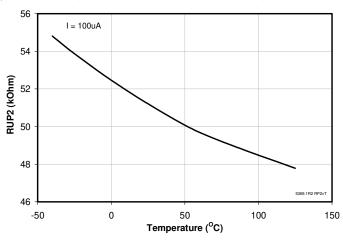
Series Resistance vs. Temperature



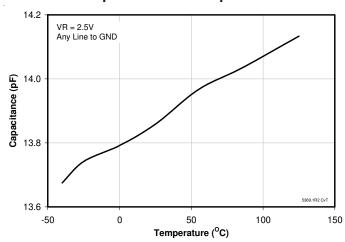
Pull Up Resistance (Rup1) vs. Temperature



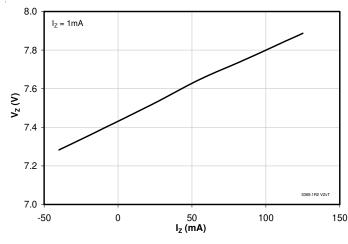
Pull Up Resistance (Rup2) vs. Temperature



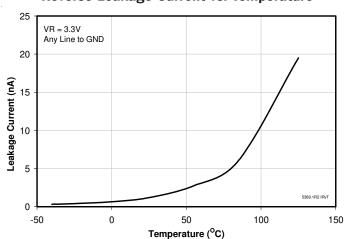
Capacitance vs. Temperature



Reverse Breakdown Voltage vs. Temperature



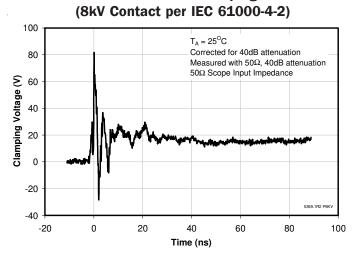
Reverse Leakage Current vs. Temperature



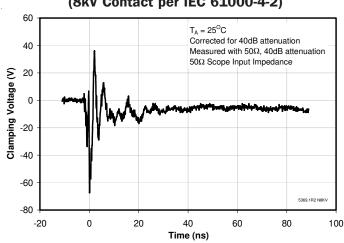


Typical Characteristics

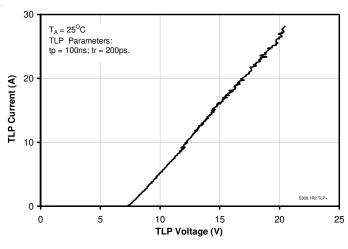
Positive ESD Clamping



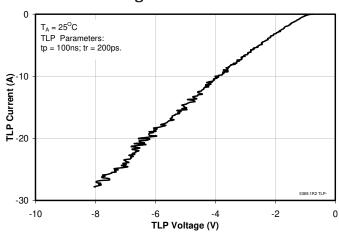
Negative ESD Clamping (8kV Contact per IEC 61000-4-2)



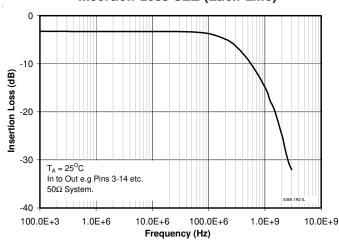
Positive TLP Plot



Negative TLP Plot



Insertion Loss S21 (Each Line)





Applications Information

Device Connection

The EClamp2410PQ is a microSD/T-Flash interface device designed for use in cell phones and other portable electronic devices. The EClamp2410PO is comprised of series and pull up resistors required on the microSD interface. Each line also includes TVS diodes for ESD protection. The device may be configured for SD or SPI mode operation. In SD mode for example, the 15k Ohm pull up resistors (Rup 1 and Rup 3) are connected to VDD. In SPI mode pin 4 is not connected (Rup 1) since these are reserved lines. The 50k Ohm pull up resistor is used for card detection or SPI mode selection during power up and is disconnected by the user during regular data transfer. The EClamp2410PO is in a 16-pin SLP package. Electrical connection is made to the 16 pins located at the bottom of the device. The device has a flow through design for easy layout. Pin connections are noted in Figure 1. A center tab serves as the ground connection. Recommendations for the ground connection are given below.

Ground Connection Recommendation

Parasitic inductance present in the board layout will affect the filtering and ESD performance of the device. Ground loop inductance can be reduced by using multiple vias to make the connection to the ground plane. Figure 2 shows the recommended device layout. The ground pad vias have a diameter of 0.008 inches (0.20 mm) while the two external vias have a diameter of 0.010 inches (0.250mm). The internal vias are spaced approximately evenly from the center of the pad. The designer may choose to use more vias with a smaller diameter (such as 0.005 inches or 0.125mm) since changing the diameter of the via will result in little change in inductance.

Layout Guidelines for Optimum ESD Protection

Good circuit board layout is critical not only for signal integrity, but also for effective suppression of ESD induced transients. For optimum ESD protection, the following guidelines are recommended:

1: Place the device as close to the connector as possible. This practice restricts ESD coupling into adjacent traces and reduces parasitic inductance.

Figure 1 - Pin Identification and Configuration (Top Side View)

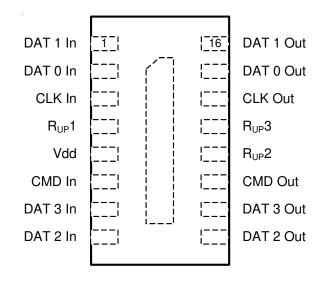
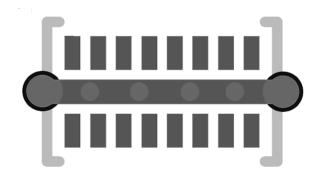


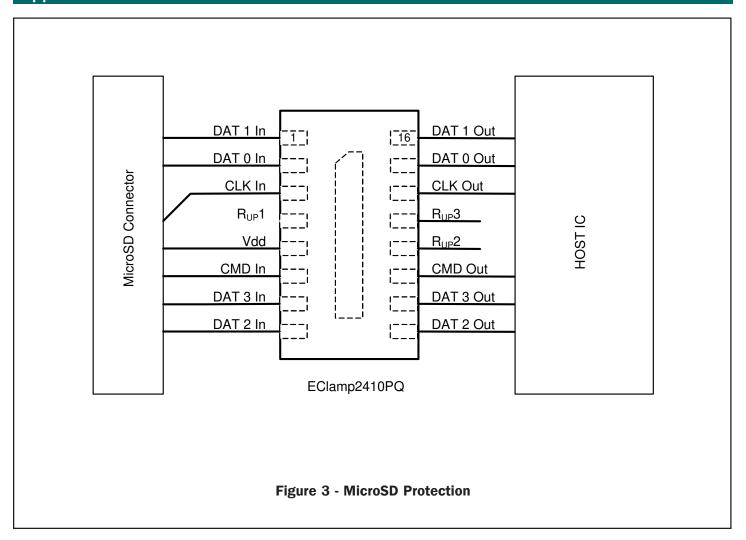
Figure 2 - Recommended Layout using Ground Vias



- 2: The ESD transient return path to ground should be kept as short as possible. Whenever possible, use multiple micro vias connected directly from the device ground pad to the ground plane.
- 3: Avoid running critical signals near board edges.

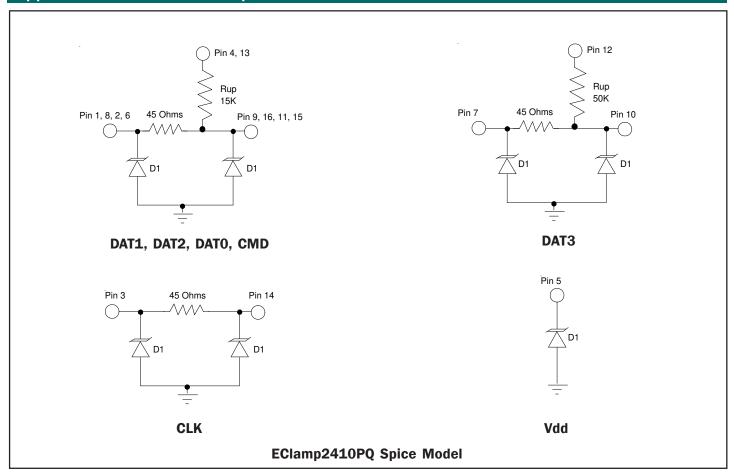


Applications Information





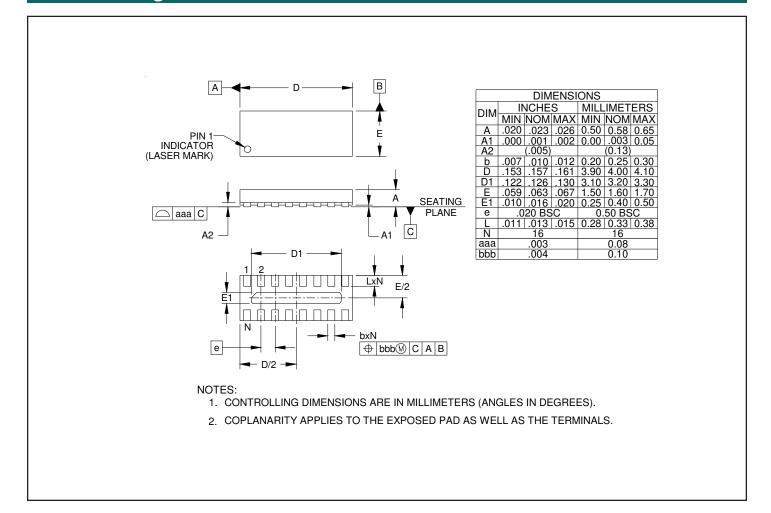
Applications Information - Spice Model



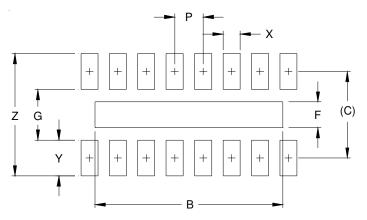
EClamp2410PQ Spice Parameters							
Parameter	Unit	D1 (TVS)					
IS	Amp	2E-15					
BV	Volt	7.46					
٧J	Volt	0.777					
RS	Ohm	1.00					
IBV	Amp	1E-3					
CJO	Farad	10E-12					
TT	sec	2.541E-9					
M		0.246					
N		1.1					
EG	eV	1.11					



Outline Drawing - SLP4016P16



Land Pattern - SLP4016P16



	DIMENSIONS								
DIM	INCHES	MILLIMETERS							
В	.130	3.30							
С	.060	1.52							
F	.018	0.45							
G	.035	0.89							
Р	.020	0.50							
X	.012	0.30							
Υ	.025	0.63							
Z	.085	2.15							

NOTES:

1. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.



Marking

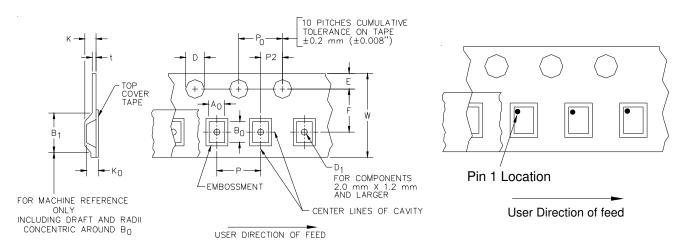
Pin 1 Indicator Laser Mark YX = Coded Date Code Pin 1 Indicator 2410 YX

Ordering Information

Part Number	Qty per Reel	Reel Size		
EClamp2410PQTCT	3000	7 Inch		

EMIClamp and EClamp are marks of Semtech Corporation

Tape and Reel Specification



Device Orientation in Tape

A0	во	ко
1.78 +/-0.10 mm	4.30 +/-0.10 mm	0.74 +/-0.10 mm

Tape Width	B, (Max)	D	D1	E	F	K (MAX)	Р	PO	P2	T(MAX)	W
12 mm	8.2 mm (.476)	1.5 + 0.1 mm - 0.0 mm (0.59 +.005 000)	1.0 mm ±0.05 (.039)	1.750±.10 mm (.069±.004)	5.5±0.05 mm (.217±.002)	4.5 mm (.177)	4.0±0.1 mm (.157±.00- 4)	4.0±0.1 mm (.157±.00- 4)	2.0±0.05m- m (.079±.002)	0.4 mm (.016)	12.0 mm + 0.3 mm - 0.1 mm (.472±.012)

Contact Information

Semtech Corporation Protection Products Division 200 Flynn Rd., Camarillo, CA 93012 Phone: (805)498-2111 FAX (805)498-3804